



# BT151X-800R

SCR

16 March 2014

Product data sheet

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring high bidirectional blocking voltage and high current surge capability with high thermal cycling performance.

## 2. Features and benefits

- High bidirectional blocking voltage capability
- High current surge capability
- High thermal cycling performance
- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability

## 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

## 4. Quick reference data

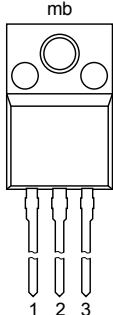

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	-	800	V
$V_{RRM}$	repetitive peak reverse voltage		-	-	800	V
$I_{TSM}$	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25\text{ °C}$ ; $t_p = 10\text{ ms}$ ; <a href="#">Fig. 4</a> ; <a href="#">Fig. 5</a>	-	-	120	A
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_h \leq 69\text{ °C}$ ; <a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>	-	-	12	A
<b>Static characteristics</b>						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>	-	2	15	mA



## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p>TO-220F (SOT186A)</p>	
2	A	anode		
3	G	gate		
mb	n.c.	mounting base; isolated		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BT151X-800R	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A
BT151X-800R/DG	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A

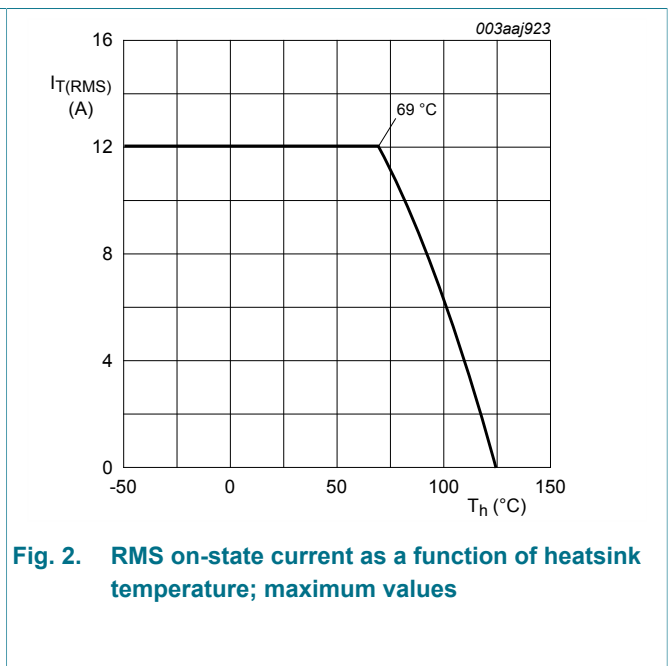
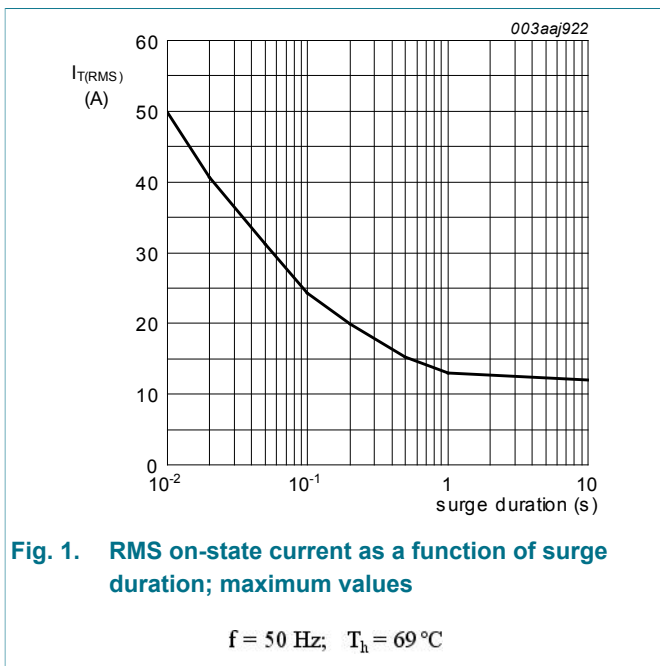
## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	800	V
$V_{RRM}$	repetitive peak reverse voltage		-	800	V
$I_{T(AV)}$	average on-state current	half sine wave; $T_n \leq 69\text{ }^\circ\text{C}$	-	7.5	A
$I_{T(RMS)}$	RMS on-state current	half sine wave; $T_n \leq 69\text{ }^\circ\text{C}$ ; <a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>	-	12	A
$I_{TSM}$	non-repetitive peak on-state current	half sine wave; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$ ; $t_p = 10\text{ ms}$ ; <a href="#">Fig. 4</a> ; <a href="#">Fig. 5</a>	-	120	A
		half sine wave; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$ ; $t_p = 8.3\text{ ms}$	-	132	A
$I^2t$	$I^2t$ for fusing	$t_p = 10\text{ ms}$ ; SIN	-	72	$\text{A}^2\text{s}$

Symbol	Parameter	Conditions	Min	Max	Unit
$di_T/dt$	rate of rise of on-state current	$I_T = 20\text{ A}$ ; $I_G = 50\text{ mA}$ ; $di_G/dt = 50\text{ mA}/\mu\text{s}$	-	50	A/ $\mu\text{s}$
$I_{GM}$	peak gate current		-	2	A
$V_{RGM}$	peak reverse gate voltage		-	5	V
$P_{GM}$	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
$T_{stg}$	storage temperature		-40	150	$^{\circ}\text{C}$
$T_j$	junction temperature		-	125	$^{\circ}\text{C}$



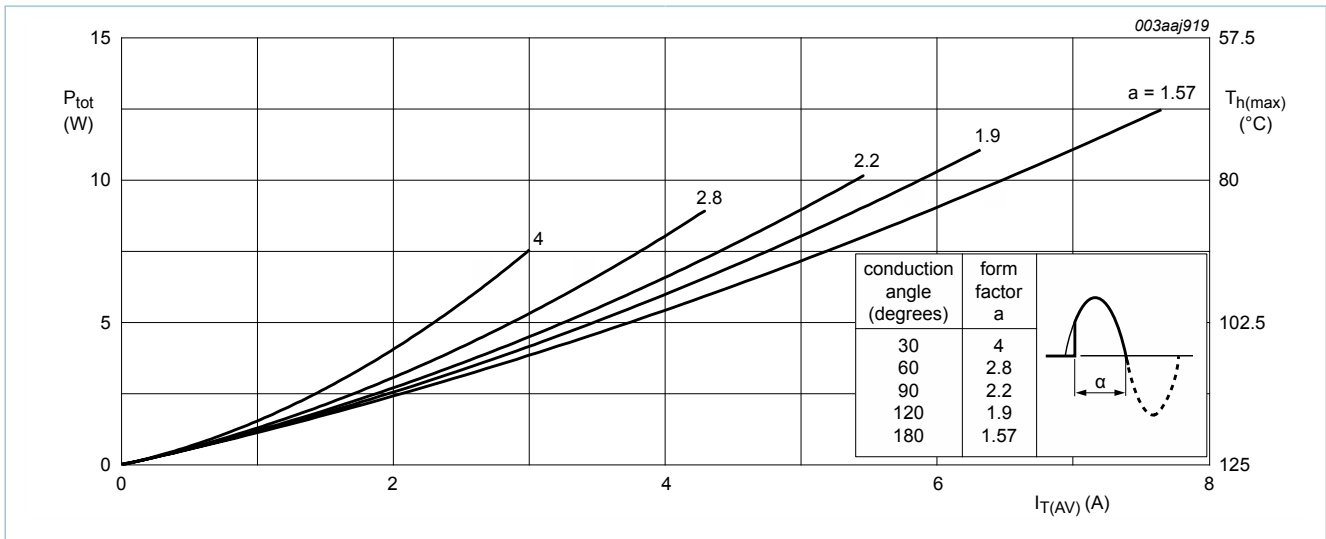


Fig. 3. Total power dissipation as a function of average on-state current; maximum values

$$\alpha = \text{conduction angle} \quad a = \text{form factor} = I_{T(RMS)} / I_{T(AV)}$$

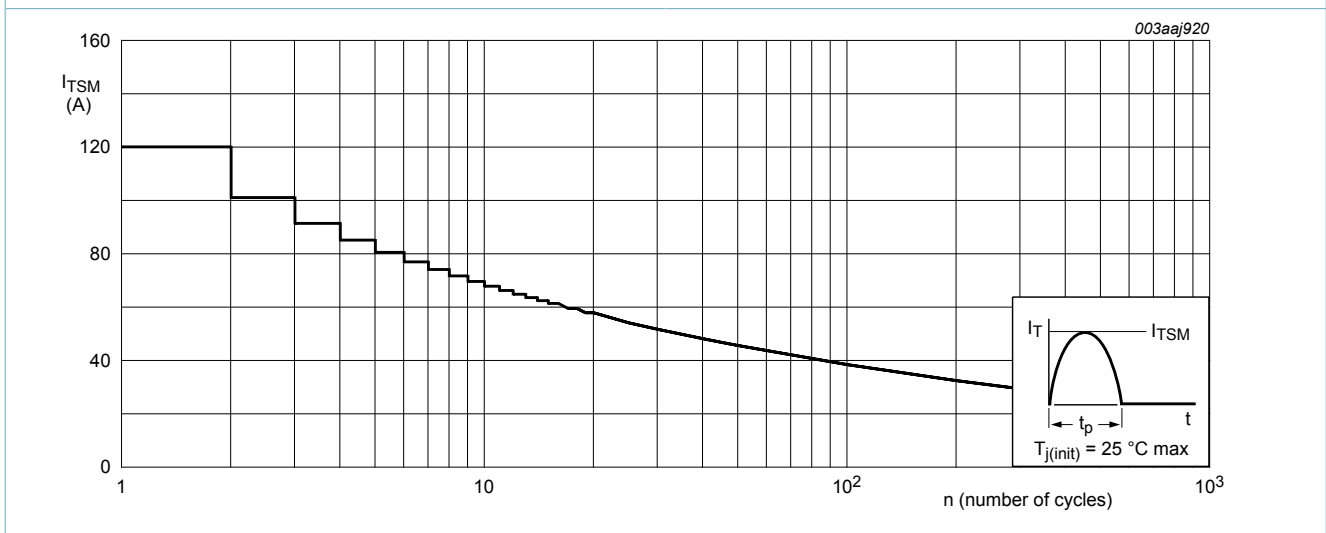
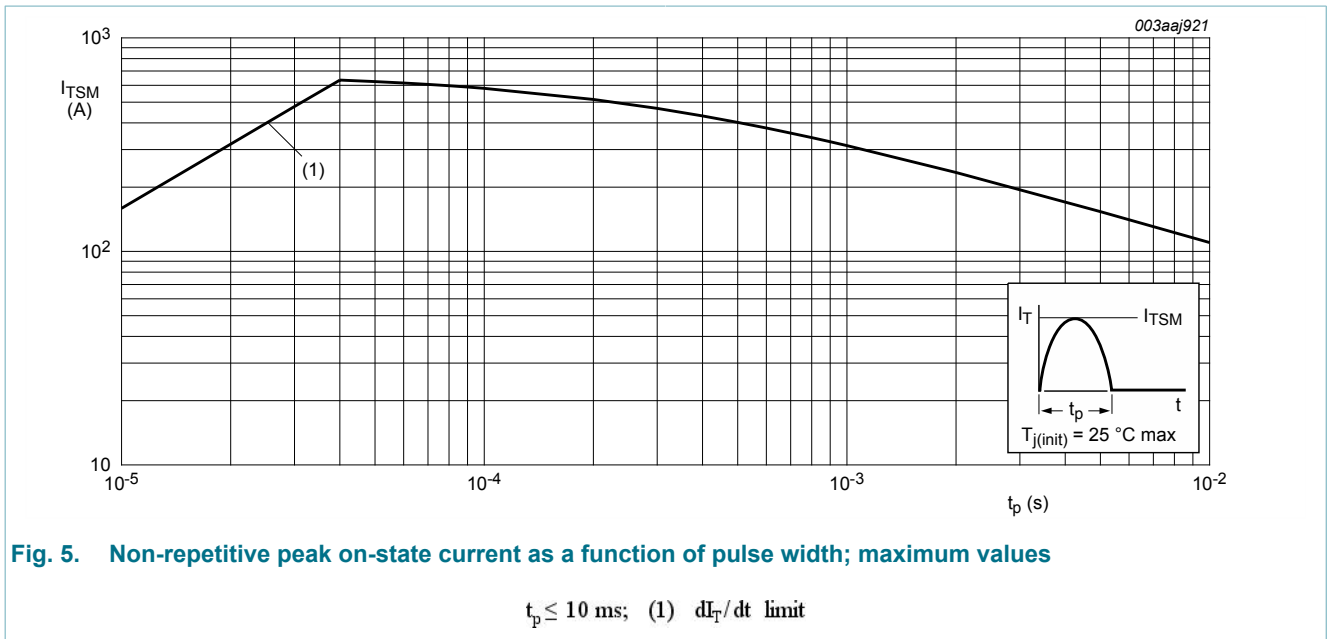


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

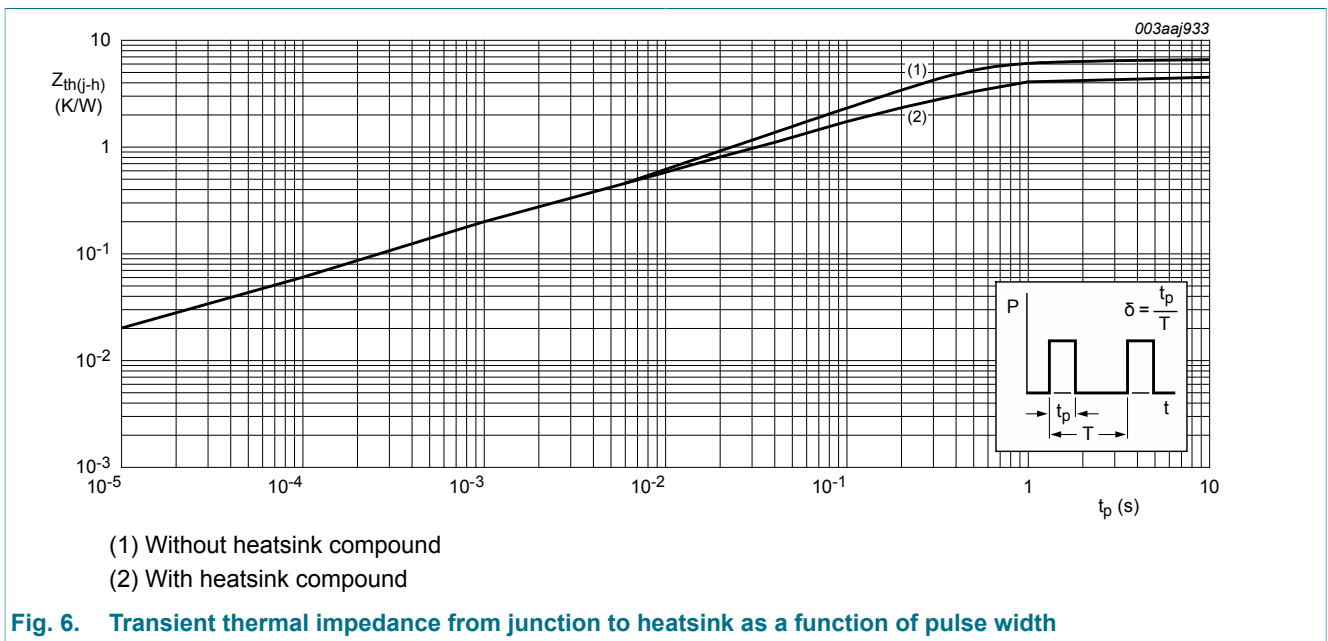
f = 50 Hz



## 8. Thermal characteristics

**Table 5. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; <a href="#">Fig. 6</a>	-	-	4.5	K/W
		without heatsink compound; <a href="#">Fig. 6</a>	-	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W



## 9. Isolation characteristics

Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{\text{iso(RMS)}}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; $50 \text{ Hz} \leq f \leq 60 \text{ Hz}$ ; $\text{RH} \leq 65 \%$ ; $T_h = 25 \text{ }^\circ\text{C}$	-	-	2500	V
$C_{\text{isol}}$	isolation capacitance	from anode to external heatsink; $f = 1 \text{ MHz}$ ; $T_h = 25 \text{ }^\circ\text{C}$	-	10	-	pF

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{\text{GT}}$	gate trigger current	$V_D = 12 \text{ V}$ ; $I_T = 0.1 \text{ A}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 7</a>	-	2	15	mA
$I_L$	latching current	$V_D = 12 \text{ V}$ ; $I_G = 0.1 \text{ A}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 8</a>	-	10	40	mA
$I_H$	holding current	$V_D = 12 \text{ V}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 9</a>	-	7	20	mA
$V_T$	on-state voltage	$I_T = 23 \text{ A}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 10</a>	-	1.4	1.75	V
$V_{\text{GT}}$	gate trigger voltage	$V_D = 12 \text{ V}$ ; $I_T = 0.1 \text{ A}$ ; $T_j = 25 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a>	-	0.6	1	V
		$V_D = 800 \text{ V}$ ; $I_T = 0.1 \text{ A}$ ; $T_j = 125 \text{ }^\circ\text{C}$ ; <a href="#">Fig. 11</a>	0.25	0.4	-	V
$I_D$	off-state current	$V_D = 800 \text{ V}$ ; $T_j = 125 \text{ }^\circ\text{C}$	-	0.1	0.5	mA
$I_R$	reverse current	$V_R = 800 \text{ V}$ ; $T_j = 125 \text{ }^\circ\text{C}$	-	0.1	0.5	mA
<b>Dynamic characteristics</b>						
$dV_D/dt$	rate of rise of off-state voltage	$V_{\text{DM}} = 536 \text{ V}$ ; $T_j = 125 \text{ }^\circ\text{C}$ ; $R_{\text{GK}} = 100 \text{ } \Omega$ ; ( $V_{\text{DM}} = 67\%$ of $V_{\text{DRM}}$ ); exponential waveform; gate open circuit; <a href="#">Fig. 12</a>	200	1000	-	V/ $\mu\text{s}$
		$V_{\text{DM}} = 536 \text{ V}$ ; $T_j = 125 \text{ }^\circ\text{C}$ ; ( $V_{\text{DM}} = 67\%$ of $V_{\text{DRM}}$ ); exponential waveform; <a href="#">Fig. 12</a>	50	130	-	V/ $\mu\text{s}$
$t_{\text{gt}}$	gate-controlled turn-on time	$I_{\text{TM}} = 40 \text{ A}$ ; $V_D = 800 \text{ V}$ ; $I_G = 100 \text{ mA}$ ; $dI_G/dt = 5 \text{ A}/\mu\text{s}$ ; $T_j = 25 \text{ }^\circ\text{C}$	-	2	-	$\mu\text{s}$
$t_q$	commutated turn-off time	$V_{\text{DM}} = 536 \text{ V}$ ; $T_j = 125 \text{ }^\circ\text{C}$ ; $I_{\text{TM}} = 20 \text{ A}$ ; $V_R = 25 \text{ V}$ ; $(dI_T/dt)_M = 30 \text{ A}/\mu\text{s}$ ; $dV_D/dt = 50 \text{ V}/\mu\text{s}$ ; $R_{\text{GK}} = 100 \text{ } \Omega$ ; ( $V_{\text{DM}} = 67\%$ of $V_{\text{DRM}}$ )	-	70	-	$\mu\text{s}$

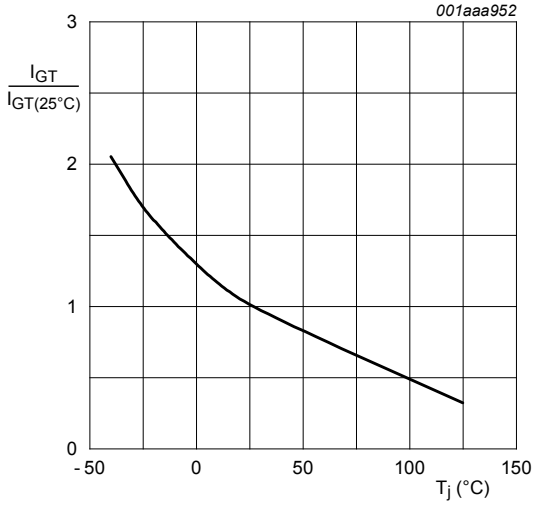


Fig. 7. Normalized gate trigger current as a function of junction temperature

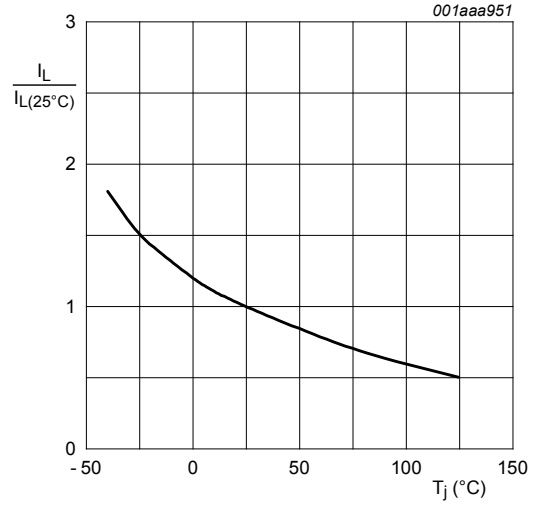


Fig. 8. Normalized latching current as a function of junction temperature

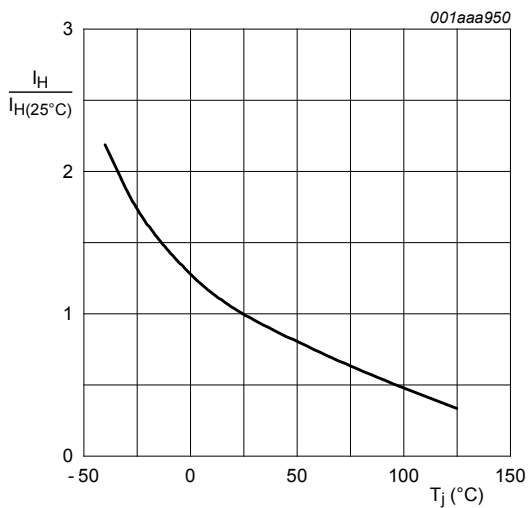
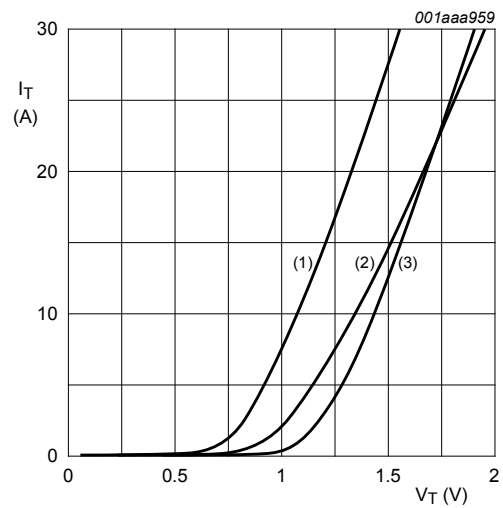


Fig. 9. Normalized holding current as a function of junction temperature



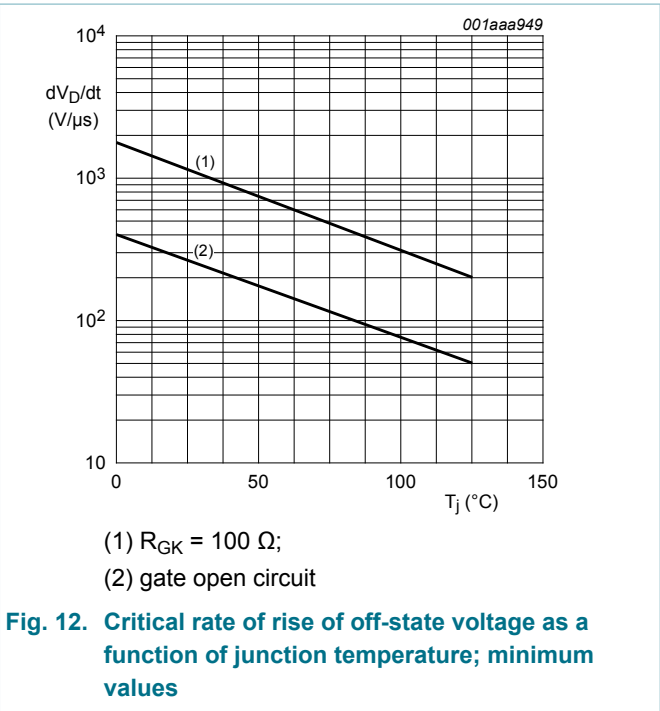
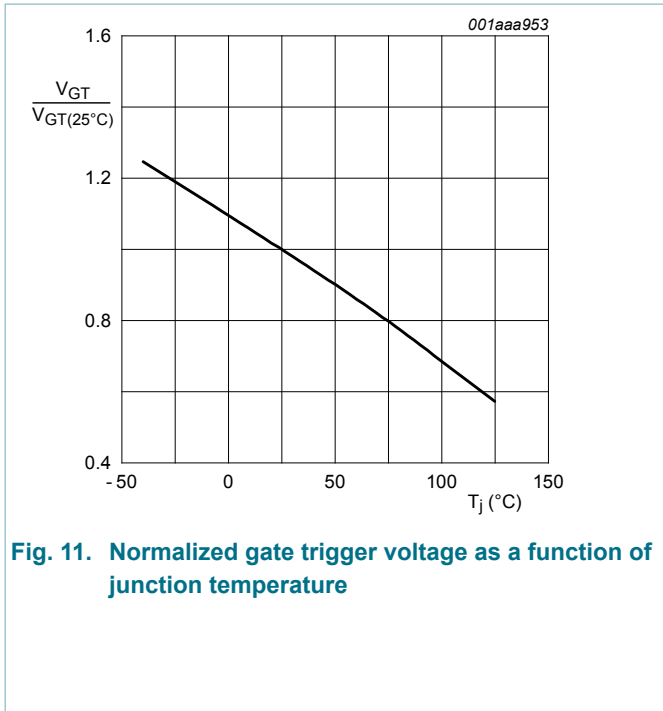
$V_o = 1.06$  V;  $R_s = 0.0304$   $\Omega$

(1)  $T_j = 125^{\circ}\text{C}$ ; typical values

(2)  $T_j = 125^{\circ}\text{C}$ ; maximum values

(3)  $T_j = 25^{\circ}\text{C}$ ; maximum values

Fig. 10. On-state current as a function of on-state voltage





### 11. Package outline

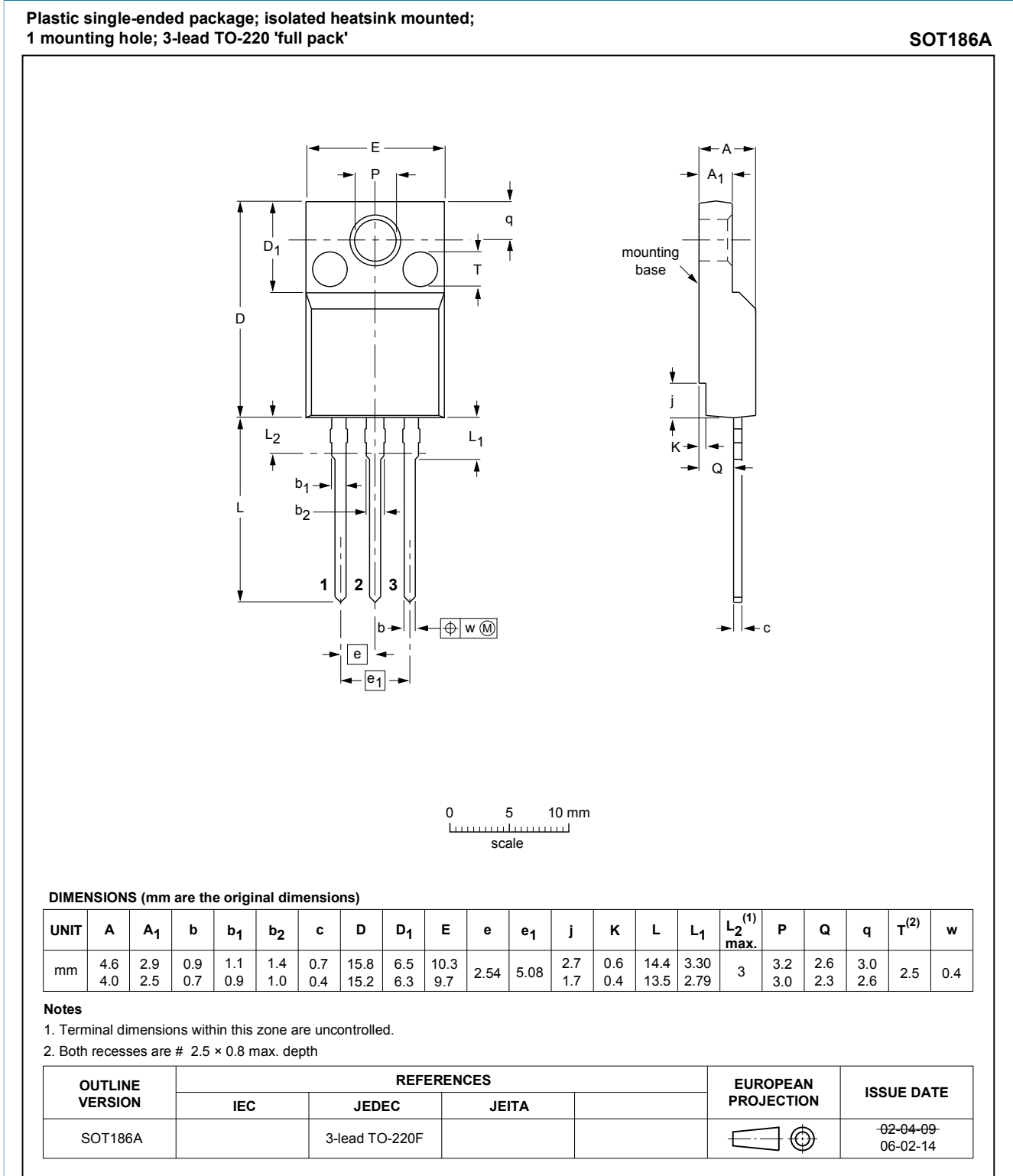


Fig. 13. Package outline TO-220F (SOT186A)

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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